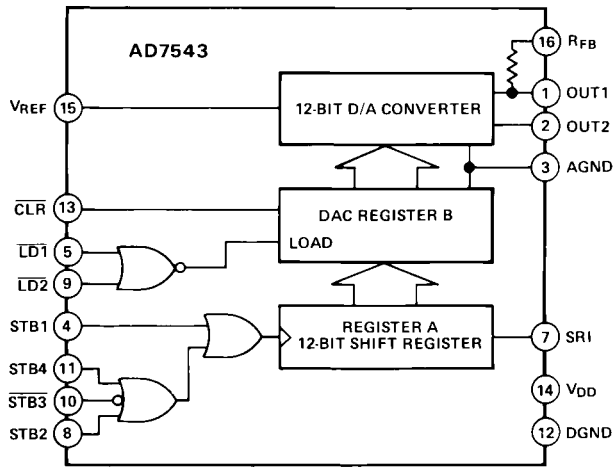
CMOS
Serial Input 12-Bit DAC

AD7543

FEATURES

Resolution: 12 Bits
Nonlinearity: ±1/2LSB T_{min} to T_{max}
Low Gain T.C.: 2ppm/°C typ, 5ppm/°C max
Serial Load on Positive or Negative Strobe
Asynchronous CLEAR Input for Initialization
Full 4-Quadrant Multiplication
Low Multiplying Feedthrough: 1LSB max @ 10kHz
Requires no Schottky Diode Output Protection
Low Power Dissipation: 40mW max
+5V Supply
Small Size: 16-Pin DIP or 20-Terminal Surface Mount Package
Low Cost

FUNCTIONAL BLOCK DIAGRAM



GENERAL DESCRIPTION

The AD7543 is a precision 12-bit monolithic CMOS multiplying DAC designed for serial interface applications.

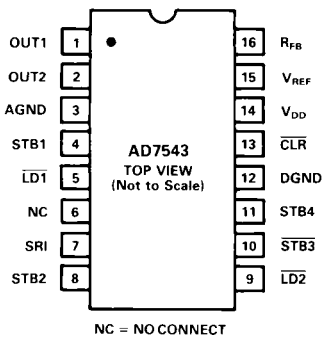
The DAC's logic circuitry consists of a 12-bit serial-in parallel-out shift register (Register A) and a 12-bit DAC input register (Register B). Serial data at the AD7543 SRI pin is clocked into Register A on the leading or trailing edge (user selected) of the strobe input. Once Register A is full its contents are loaded into Register B under control of the LOAD inputs.

Initialization is simplified by the use of the CLR input which provides an asynchronous reset of Register B.

Packaged in 16-pin DIP and 20-pin LCCC and PLCC, the AD7543 features excellent gain T.C. (2ppm/°C typ; 5ppm/°C max), +5V operation and latch-free operation. (No protection Schottky Diodes required.)

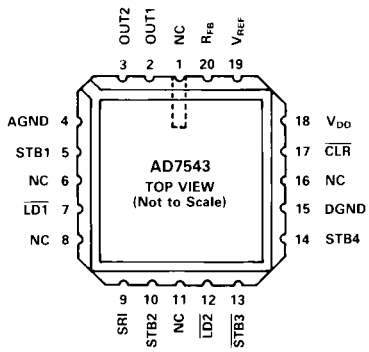
PIN CONFIGURATIONS

DIP



NC = NO CONNECT

LCCC



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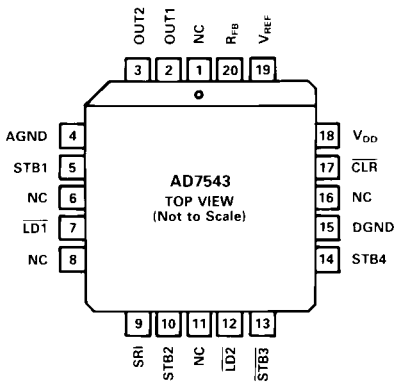
PLCC



NC = NO CONNECT

REV. B

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AD7543—SPECIFICATIONS (V_{DD} = +5V, V_{REF} = +10V, V_{OUT1} = V_{OUT2} = 0V, unless otherwise noted.)

Parameter	Limit At T_A = +25°C	Limit At[1] T_A = -40°C to +85°C	Limit At[1] T_A = -55°C & +125°C	Units	Conditions/Comments
ACCURACY					
Resolution	12	12	12	Bits	
Relative Accuracy[2]					
J, A, S Versions	±1	±1	±1	LSB max	
K, B, T Versions	±1/2	±1/2	±1/2	LSB max	
GK, GB, GT Versions	±1/2	±1/2	±1/2	LSB max	
Differential Nonlinearity[2]					
J, A, S Versions	±2	±2	±2	LSB max	Monotonic to 11 bits from T_{min} to T_{max}
K, B, T Versions	±1	±1	±1	LSB max	Monotonic to 12 bits from T_{min} to T_{max}
GK, GB, GT Versions	±1	±1	±1	LSB max	Monotonic to 12 bits from T_{min} to T_{max}
Gain Error[2]					
J, K, A, B, S, T	±12.3	±13.5	±14.5	LSB max	Using internal RFB only (gain error can be
GK, GB, GT	±1	±1	±2	LSB max	trimmed to zero using circuits of Figures 6 & 7)
Gain Temperature Coefficient					
ΔGain/ΔTemperature	5	5	5	ppm/°C max	Typical value is 2ppm/°C
Power Supply Rejection					
$\Delta Gain/\Delta V_{DD}$	0.005	0.01	0.01	% per % max	V_{DD} = +4.75V to +5.25V
Output Leakage Current					
I_{OUT1} (Pin 4)	1	10	200	nA max	DAC Register loaded with all 0s
I_{OUT2} (Pin 5)	1	10	200	nA max	DAC Register loaded with all 1s
DYNAMIC PERFORMANCE					
Current Settling Time[3]	2.0	2.0	2.0	μs max	To 1/2LSB. OUT1 load = 100Ω. DAC output measured from falling edge of $\overline{LD1}$ and $\overline{LD2}$, see Figure 5.
Multiplying Feedthrough Error[3]	2.5	2.5	2.5	mV p-p max	V_{REF} = ±10V, 10kHz sine wave
REFERENCE INPUT					
Input Resistance (pin 15)	8/15/25	8/15/25	8/15/25	kΩ min/typ/max	Typical temperature coefficient is -300ppm/°C
ANALOG OUTPUTS					
Output Capacitance					
C_{OUT1}[3]	75	75	75	pF max	Register B loaded to 0000 0000 0000
C_{OUT1}[3]	260	260	260	pF max	Register B loaded to 1111 1111 1111
C_{OUT2}[3]	75	75	75	pF max	Register B loaded to 1111 1111 1111
C_{OUT2}[3]	260	260	260	pf max	Register B loaded to 0000 0000 0000
LOGIC INPUTS					
V_{INH} (Logic HIGH Voltage)	+3.0	+3.0	+3.0	V min	
V_{INL} (Logic LOW Voltage)	+0.8	+0.8	+0.8	V max	
I_{IN}[4]	1	1	1	μA max	V_{IN} = 0V or V_{DD}
C_{IN} (Input Capacitance)[3]	8	8	8	pF max	
Input Coding	12-Bit Unipolar Binary or 12-Bit Offset Binary (see Figures 6 and 7), serial load (MSB First)				
SWITCHING CHARACTERISTICS[5]					
t_{DS1}	50	100	100	ns min	(Serial Input to Strobe Setup Time) STB1 used as a strobe
t_{DS4}	0	0	0	ns min	STB4 used as a strobe
t_{DS3}	0	0	0	ns min	$\overline{STB3}$ used as a strobe
t_{DS2}	20	40	40	ns min	STB2 used as a strobe
t_{DH1}	30	60	60	ns min	(Serial Input to Strobe Hold Time) STB1 used as a strobe
t_{DH4}	80	160	160	ns min	STB4 used as a strobe
t_{DH3}	80	160	160	ns min	$\overline{STB3}$ used as a strobe
t_{DH2}	60	120	120	ns min	STB2 used as a strobe
t_{SRI}	80	160	160	ns min	SRI data pulse width
t_{STB1}	80	160	160	ns min	STB1 pulse width
t_{STB4}	100	200	200	ns min	STB4 pulse width
t_{STB3}	100	200	200	ns min	$\overline{STB3}$ pulse width
t_{STB2}	80	160	160	ns min	STB2 pulse width
t_{LD1}, t_{LD2}	150	300	300	ns min	Load pulse width
t_{ASB}	0	0	0	ns min	Min time between strobing LSB into Register A and loading Register B
t_{CLR}	200	400	400	ns min	CLR pulse width
POWER SUPPLY					
V_{DD} (Supply Voltage)	+5	+5	+5	V	
I_{DD} (Supply Current)	2.5	2.5	2.5	mA max	Digital Inputs = V_{INH} or V_{INL}

NOTES

[1]Temperature ranges as follows: JN, KN, GKN Version; −40°C to +85°C
AQ, BQ, GBQ Versions: −40°C to +85°C
SQ, TQ, GTQ Versions: −55°C to +125°C

[2]See Terminology on following page.

[3]Guaranteed but not tested.

[4]Logic inputs are MOS gates. Typical input current (+25°C) is less than 1nA.

[5]Sample tested at +25°C to ensure compliance.

Specifications subject to change without notice.

ABSOLUTE MAXIMUM RATINGS*

(T_A = +25°C unless otherwise noted)

V_{DD} to AGND	0V, +7V
V_{DD} to DGND	0V, +7V
AGND to DGND	V_{DD} +0.3V
DGND to AGND	V_{DD} +0.3V
Digital Input Voltage to DGND	−0.3V, V_{DD} +0.3V
V_{OUT1}, V_{OUT2} to AGND	−0.3V, V_{DD} to +0.3V
V_{REF} to AGND	±25V
V_{RFB} to AGND	±25V
Power Dissipation (Package)	
Plastic	
To +70°C	670mW
Derates above +70°C by	8.3mW/°C
Cerdip	
To +75°C	450mW
Derates above +75°C by	6mW/°C
Operating Temperature Range	
Commercial (J, K, GK Versions)	−40°C to +85°C
Industrial (A, B, GB Versions)	−40°C to +85°C
Extended (S, T, GT Versions)	−55°C to +125°C
Storage Temperature	−65°C to +150°C
Lead Temperature (Soldering, 10secs)	+300°C

*Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ORDERING GUIDE

Model	Temperature Range	Relative Accuracy	Gain Error	Package Option*
AD7543JN	−40°C to +85°C	±1LSB	±12.3LSB	N-16
AD7543KN	−40°C to +85°C	±1/2LSB	±12.3LSB	N-16
AD7543GKN	−40°C to +85°C	±1/2LSB	±1LSB	N-16
AD7543JP	−40°C to +85°C	±1LSB	±12.3LSB	P-20A
AD7543KP	−40°C to +85°C	±1/2LSB	±12.3LSB	P-20A
AD7543GKP	−40°C to +85°C	±1/2LSB	±1LSB	P-20A
AD7543JR	−40°C to +85°C	±1LSB	±12.3LSB	R-16
AD7543KR	−40°C to +85°C	±1/2LSB	±12.3LSB	R-16
AD7543GKR	−40°C to +85°C	±1/2LSB	±1LSB	R-16
AD7543AQ	−40°C to +85°C	±1LSB	±12.3LSB	Q-16
AD7543BQ	−40°C to +85°C	±1/2LSB	±12.3LSB	Q-16
AD7543GBQ	−40°C to +85°C	±1/2LSB	±1LSB	Q-16
AD7543SQ	−55°C to +125°C	±1LSB	±12.3LSB	Q-16
AD7543TQ	−55°C to +125°C	±1/2LSB	±12.3LSB	Q-16
AD7543GTQ	−55°C to +125°C	±1/2LSB	±1LSB	Q-16
AD7543SE	−55°C to +125°C	±1LSB	±12.3LSB	E-20A
AD7543TE	−55°C to +125°C	±1/2LSB	±12.3LSB	E-20A
AD7543GTE	−55°C to +125°C	±1/2LSB	±1LSB	E-20A

*E = Leadless Ceramic Chip Carrier (LCCC); N = Plastic DIP; P = Plastic Leaded Chip Carrier (PLCC); Q = Cerdip; R = Small Outline IC (SOIC).

CAUTION

ESD (electrostatic discharge) sensitive device. The digital control inputs are diode protected; however, permanent damage may occur on unconnected devices subject to high energy electrostatic fields. Unused devices must be stored in conductive foam or shunts. The protective foam should be discharged to the destination socket before devices are removed.

PIN	MNEMONIC	FUNCTION
1	OUT1	DAC current output bus. Normally terminated at op amp virtual ground
2	OUT2	DAC current output bus. Normally terminated at AGND
3	AGND	Analog Ground
4	STB1	Register A Strobe 1 input, see Table II
5	$\overline{LD1}$	DAC Register B Load 1 input. When $\overline{LD1}$ and $\overline{LD2}$ go low the contents of Register A are loaded into DAC Register B
6	N/C	No Connection
7	SRI	Serial Data Input to Register A
8	STB2	Register A Strobe 2 input, see Table II
9	$\overline{LD2}$	DAC Register B Load 2 input. When $\overline{LD1}$ and $\overline{LD2}$ go low the contents of Register A are loaded into DAC Register B
10	$\overline{STB3}$	Register A Strobe 3 input, see Table II
11	STB4	Register A Strobe 4 input, see Table II
12	DGND	Digital Ground
13	$\overline{CLR}$	Register B CLEAR input (active LOW), can be used to asynchronously reset Register B to 0000 0000 0000
14	V_{DD}	+5V Supply Input
15	V_{REF}	Reference input. Can be positive or negative dc voltage or ac signal
16	R_{FB}	DAC Feedback Resistor

Table I. Pin Function Description, DIP Configuration

TERMINOLOGY

RELATIVE ACCURACY
Relative accuracy or endpoint nonlinearity is a measure of the maximum deviation from a straight line passing through the endpoints of the DAC transfer function. It is measured after adjusting for ideal zero and full scale and is expressed in % or ppm of full-scale range or (sub) multiples of 1LSB.

DIFFERENTIAL NONLINEARITY
Differential nonlinearity is the difference between the *measured* change and the *ideal* 1 LSB change between any two adjacent codes. A specified differential nonlinearity of ±1 LSB max over the operating temperature range ensures monotonicity.

GAIN ERROR
Gain is defined as the ratio of the DAC's Full Scale output to its reference input voltage. An *ideal* AD7543 would exhibit a gain of -4095/4096. Gain error is adjustable using external trims as shown in Figures 6 and 7.

OUTPUT LEAKAGE CURRENT
Current which appears at OUT1 with Register B loaded to all 0's or at OUT 2 with Register B loaded to all 1's.

MULTIPLYING FEEDTHROUGH ERROR
AC error due to capacitive feedthrough from V_{REF} terminal to OUT1 with DAC register loaded to all 0's.

GENERAL CIRCUIT INFORMATION
The AD7543, a 12-bit multiplying D/A converter, consists of a highly stable thin film R-2R ladder and twelve N-channel current switches on a monolithic chip. Most applications require the addition of only an output operational amplifier and a voltage or current reference.

The simplified D/A circuit is shown in Figure 1. An inverted R-2R ladder structure is used—that is, the binarily weighted currents are switched between the OUT1 and OUT2 bus lines, thus maintaining a constant current in each ladder leg independent of the switch state.

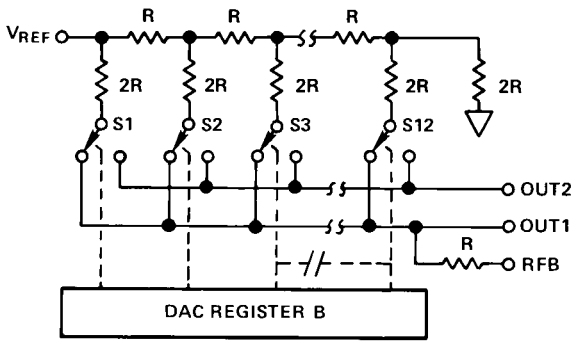


Figure 1. AD7543 Functional Diagram

One of the current switches is shown in Figure 2. The input resistance at V_{REF} (Figure 2) is always equal to R_{LDR} (R_{LDR} is the R/2R ladder characteristic resistance and is equal to value "R"). The reference terminal can be driven by a reference voltage or a reference current, ac or dc, of positive or negative polarity. If a current source is used, a low temperature coefficient external R_{FB} is recommended to define scale factor.

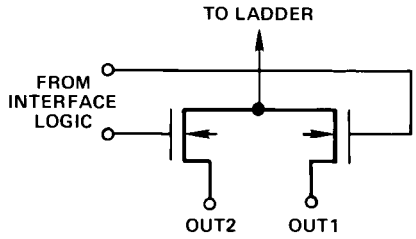


Figure 2. N-Channel Current Steering Switch

EQUIVALENT CIRCUIT ANALYSIS
The equivalent circuits for all digital inputs LOW and all digital inputs HIGH are shown in Figures 3 and 4. In Figure 3 with all digital inputs LOW, the reference current is switched to OUT2. The current source $I_{LEAKAGE}$ is composed of surface and junction leakages to the substrate, while the I/4096 current source represents a constant 1 least significant bit current drain through the termination resistor on the R-2R ladder. The "ON" capacitance of the output N-channel switch is 260pF, as shown on the OUT2 terminal. The "OFF" switch capacitance is 75pF, as shown on the OUT1 terminal. Analysis of the circuit for all digital inputs HIGH, as shown in Figure 4, is similar to Figure 3; however, the "ON" switches are now on terminal OUT1, hence the 260pF at that terminal.

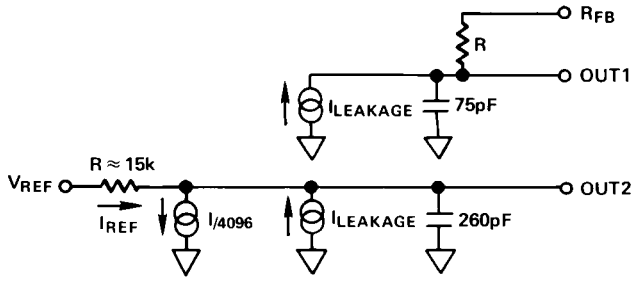


Figure 3. AD7543 DAC Equivalent Circuit All Digital Inputs LOW

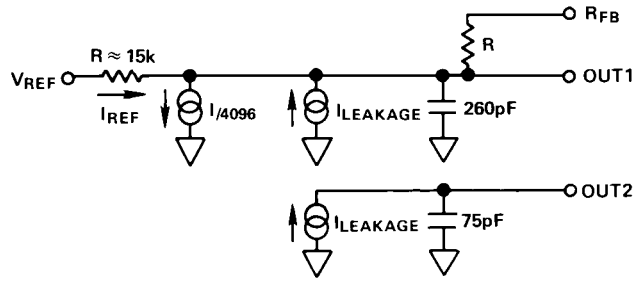


Figure 4. AD7543 DAC Equivalent Circuit All Digital Inputs HIGH

AD7543 Logic Inputs							AD7543 Operation	Notes
Register A Control Inputs				Register B Control Inputs				
STB4	$\overline{STB3}$	STB2	STB1	$\overline{CLR}$	$\overline{LD2}$	$\overline{LD1}$		
0	1	0	↓	X	X	X	Data Appearing At SRI Strobed Into Register A	2,3
0	1	↓	0	X	X	X	Data Appearing At SRI Strobed Into Register A	2,3
0	↑	0	0	X	X	X	Data Appearing At SRI Strobed Into Register A	2,3
↓	1	0	0	X	X	X	Data Appearing At SRI Strobed Into Register A	2,3
1	X	X	X				No Operation (Register A)	3
X	0	X	X					
X	X	1	X					
X	X	X	1					
				0	X	X	Clear Register B To Code 0000 0000 0000 (Asynchronous Operation)	1,3
				1	1	X	No Operation (Register B)	3
				1	X	1		
				1	0	0	Load Register B With The Contents Of Register A	3

NOTES:
1. CLR = 0 Asynchronously resets Register B to 0000 0000 0000, but has no effect on Register A.
2. Serial data is loaded into Register A MSB first, on edges shown ↓ is positive edge ↑ is negative edge.
3. 0 = Logic LOW, 1 = Logic HIGH, X = Don't Care.

Table II. AD7543 Truth Table

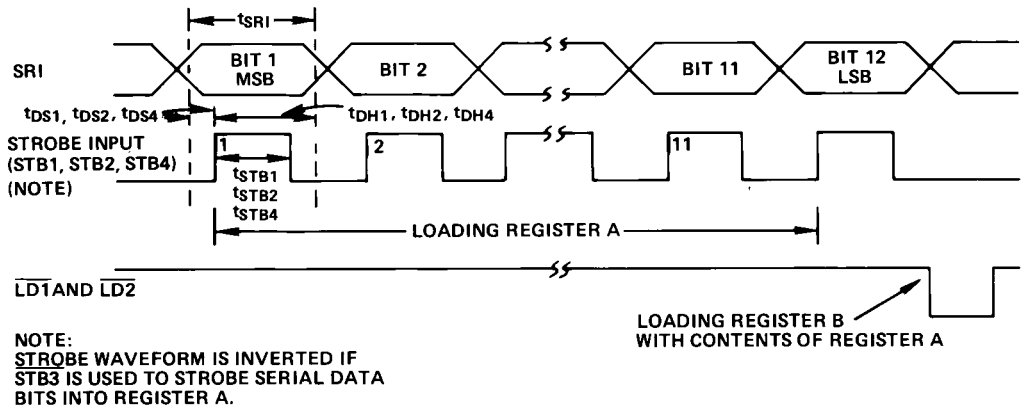


Figure 5. Timing Diagram

INTERFACE LOGIC INFORMATION

Shown in the AD8543 Functional Diagram Register A is a 12-bit shift register. Serial data appearing at pin SR1 is clocked into the shift register on the leading (rising) edge of STB1, STB2 or STB4 or on the leading (falling) edge of $\overline{STB3}$. Table II defines the various logic states required on the Register A control inputs, while Figure 5 illustrates the Register A loading sequence.

Once Register A is full, the data is transferred to Register B by bringing $\overline{LD1}$ and $\overline{LD2}$ momentarily LOW.

Register B can be asynchronously reset to 0000 0000 0000 by bringing $\overline{CLR}$ momentarily LOW. This allows the DAC output voltage to be set to a known condition, thus simplifying system initialization procedure. When operating the AD7543 in the unipolar circuit of Figure 6, a CLEAR causes the DAC output voltage to equal 0V. When using the bipolar circuit of Figure 7, a CLEAR causes the DAC output to equal $-V_{REF}$.

APPLYING THE AD7543

UNIPOLAR BINARY OPERATION (2-QUADRANT MULTIPLICATION)

Figure 6 shows the analog circuit connections required for unipolar binary (2-quadrant multiplication) operation. The logic inputs are omitted for clarity. With a dc reference voltage or current (positive or negative polarity) applied at pin 15, the circuit is a unipolar D/A converter. With an ac reference voltage or current (again of + or - polarity) the circuit provides 2-quadrant multiplication (digitally controlled attenuation). The input/output relationship is shown in Table III.

R1 provides full scale trim capability [i.e.—load the DAC register to 1111 1111 1111, adjust R1 for $V_{OUT} = -V_{REF}$ (4095/4096)]. Alternatively, Full Scale can be adjusted by omitting R1 and R2 and trimming the reference voltage magnitude.

C1 phase compensation (10pF to 25pF) may be required for stability when using high speed amplifiers. (C1 is used to cancel the pole formed by the DAC internal feedback resistance and output capacitance at OUT1).

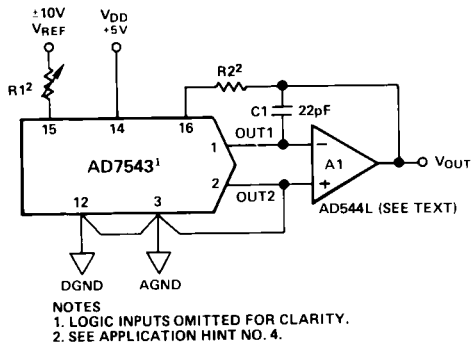


Figure 6. Unipolar Binary Operation (2-Quadrant Multiplication)

BINARY NUMBER IN DAC REGISTER MSB LSB	ANALOG OUTPUT, V_{OUT}
1111 1111 1111	$-V_{REF}\left(\frac{4095}{4096}\right)$
1000 0000 0000	$-V_{REF}\left(\frac{2048}{4096}\right) = -1/2\ V_{REF}$
0000 0000 0001	$-V_{REF}\left(\frac{1}{4096}\right)$
0000 0000 0000	0V

Table III. Unipolar Binary Code Table for Circuit of Figure 6

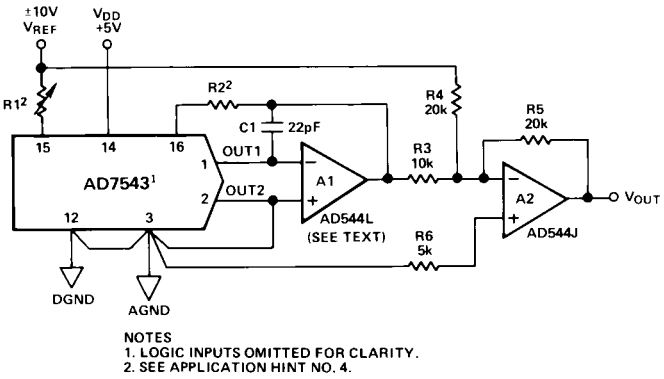


Figure 7. Bipolar Operation (4-Quadrant Multiplication)

BINARY NUMBER IN DAC REGISTER MSB LSB	ANALOG OUTPUT, V_{OUT}
1111 1111 1111	$+V_{REF}\left(\frac{2047}{2048}\right)$
1000 0000 0001	$+V_{REF}\left(\frac{1}{2048}\right)$
1000 0000 0000	0V
0111 1111 1111	$-V_{REF}\left(\frac{1}{2048}\right)$
0000 0000 0000	$-V_{REF}\left(\frac{2048}{2048}\right)$

Table IV. Bipolar Code Table for Offset Binary Circuit of Figure 7

Amplifier A1 should be selected or trimmed to provide $V_{OS} \leq 10\%$ of the voltage resolution at V_{OUT}. Additionally, the amplifier should exhibit a bias current which is low over the temperature range of interest (bias current causes output offset at V_{OUT} equal to I_B times the DAC feedback resistance, nominally 15kΩ). The AD544L is a high-speed implanted FET-input op amp with low, factory-trimmed V_{OS}.

BIPOLAR OPERATION (4-QUADRANT MULTIPLICATION)

Figure 7 and Table IV illustrate the circuitry and code relationship for bipolar operation. With a dc reference (positive or negative polarity) the circuit provides offset binary operation. With an ac reference, the eleven LSBs provide digitally controlled attenuation of the ac reference while the MSB provides polarity control.

With the DAC register loaded to 1000 0000 0000, adjust R1 for V_{OUT} = 0V (alternatively, one can omit R1 and R2 and adjust the ratio of R3 to R4 for V_{OUT} = 0V). Full scale trimming can be accomplished by adjusting the amplitude of V_{REF} or by varying the value of R5.

As in unipolar operation, A1 must be chosen for low V_{OS} and low I_B. R3, R4 and R5 must be selected for matching and tracking. Mismatch of 2R3 to R4 causes both offset and Full Scale error. Mismatch of R5 to R4 to 2R3 causes Full Scale error. C1 phase compensation (10pF to 25pF) may be required for stability.

APPLICATION HINTS

The AD7543 is a precision 12-bit multiplying DAC designed for serial interface. To ensure system performance consistent with AD7543 specifications, careful attention must be given to the following points:

1. GENERAL GROUND MANAGEMENT: Voltage differences between the AD7543 AGND and DGND cause loss of accuracy (dc voltage difference between the grounds introduces gain error. AC or transient voltages between the grounds cause noise injection into the analog output). The simplest method of ensuring that voltages at AGND and DGND are equal is to tie AGND and DGND together at the AD7543. In more complex systems where the AGND-DGND connection is on the back-plane, it is recommended that diodes be connected back-to-back between the AD7543 AGND and DGND pins to prevent possible device damage.
2. OUTPUT AMPLIFIER OFFSET: CMOS DACs exhibit a code-dependent output resistance which in turn causes a code-dependent amplifier noise gain. The effect is a differential nonlinearity term at the amplifier output which depends on V_{OS} (V_{OS} is amplifier input offset voltage). This differential nonlinearity term adds to the R/2R differential nonlinearity. To maintain monotonic operation, it is recommended that amplifier V_{OS} be no greater than 10% of the DAC's output resolution over the temperature range of interest [output resolution = $V_{REF}\ 2^{-n}$ where n is the number of bits exercised].

3. HIGH FREQUENCY CONSIDERATIONS: AD7543 output capacitance works in conjunction with the amplifier feedback resistance to add a pole to the open loop response. This not only reduces closed loop bandwidth, but can also cause ringing or oscillation if the spurious pole frequency is less than the amplifier's 0dB crossover frequency. Stability can be restored by adding a phase compensation capacitor in parallel with the feedback resistor.
4. GAIN TEMPERATURE COEFFICIENTS: The gain temperature coefficient of the AD7543 has a maximum value of 5ppm/°C and a typical value of 2ppm/°C. This corresponds to gain shifts of 2.0LSBs and 0.82LSBs respectively over a 100°C temperature range. When trim resistors are used to adjust full-scale range as shown in Figures 6 and 7 the temperature coefficient of R1 and R2 should be taken into account. It may be shown that the additional gain temperature coefficients introduced by R1 and R2 may be approximately expressed as follows:—

$$\text{Temperature Coefficient contribution due to R1} = -\frac{R_1}{R_{IN}}(\gamma_1 + 300)$$

$$\text{Temperature Coefficient contribution due to R2} = +\frac{R_2}{R_{IN}}(\gamma_2 + 300)$$

Where γ_1 and γ_2 are the temperature coefficients in ppm/°C of R1 and R2 respectively and R_{IN} is the DAC input resistance at the V_{REF} terminal (pin 2). For high quality wirewound resistors and trimming potentiometers γ is of the order of 50ppm/°C. It will be seen that if R1 and R2 are small compared with R_{IN}, their contribution to gain temperature coefficient will also be small. For the standard AD7543 gain error specification of ±12.3LSBs it is recommended that R1 = 120Ω and R2 = 60Ω. With γ = 50 these values result in an overall maximum gain error temperature coefficient of:

$$5 + \frac{0.06}{7}(50 + 300) = 8\text{ppm/°C}$$

However, if the AD7543GTD is used which has a specified gain error of ±1LSB, then with R1 = 10Ω and R2 = 5Ω the overall maximum gain temperature coefficient is increased by only 0.25ppm/°C. Where possible R1 should be a select on test fixed resistor since the resulting gain temperature coefficient will be tighter in all cases. For further gain T.C. information refer to application note, "Gain Error and Gain Temperature Coefficients of CMOS Multiplying DACs", Publication Number E630—10—6/81 available from Analog Devices.

5. For additional information on multiplying DACS refer to "Application Guide to CMOS Multiplying D/A Converters", Publication Number G479—15—8/78, available from Analog Devices.

AD7543 INTERFACE TO MC6800

In this example, it is assumed that the 12-bit data is contained in two memory locations (0000 and 0001). The four most significant bits are assumed to occupy the lower half of memory location 0000. The eight least significant bits occupy memory location 0001. The data is presented bit by bit on the D7 line and strobed into the AD7543 by executing memory write instructions. In this case the strobe signal (STB1) is supplied by decoding address 2000, R/$\overline{W}$ and ϕ_2. A memory write instruction to a different address (4000) loads the data from Register A to the DAC register.

Figure 8 shows the interface circuitry and Table V gives a listing of the procedure.

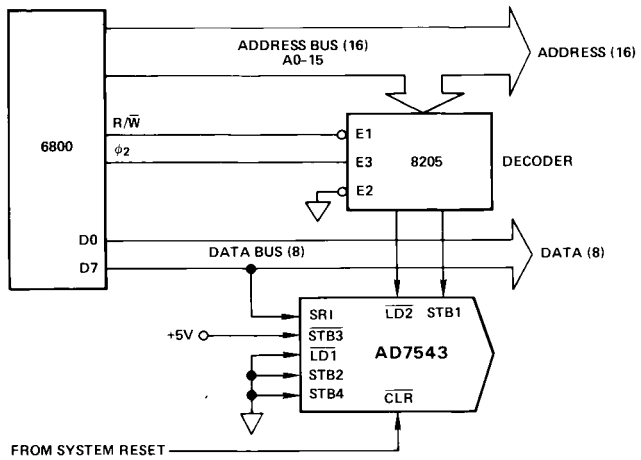


Figure 8. AD7543—MC6800 Interface

LABEL	MNEMONIC	OPERAND	COMMENT
	LDA	B, 04	
	LDA	A, 0000	Load 4 Most Significant Bits
LOOP	ROL	A	Reposition in the Data
	DEC	B	in ACC A
	BNE	LOOP	
	LDA	B, 04	
	BSR	SHIFT	Output Data
	LDA	B, 08	
	LDA	A, 0001	Load 8 Least Significant Bits
	BSR	SHIFT	Output Data
	STA	A, 4000	Load DAC Register
	RTS		Return to Main Program
SHIFT	STA	A,2000	Strobe Data
	ROL	A	into AD7543
	DEC	B	
	BNE	SHIFT	
	RTS		

Table V. Sample Routine for AD7543—MC6800 Interface

AD7543 INTERFACE TO MCS-85

Figure 9 shows the AD7543 interfaced to the 8085. This system makes use of the serial output facility (SOD) on the 8085.

The data is presented serially on the SOD line and strobed into the AD7543 by executing memory write instructions. In this example the strobe signal (STB2) is supplied by decoding address 8000 and $\overline{WR}$. A memory write instruction to a different address (A000) loads the DAC Register with Register

A data. Table VI gives a listing of this procedure. Note, it is assumed that the required serial data is already present in right-justified format in Registers H and L when this procedure is implemented. Note that the sample routine of Table VI can be speeded up by replacing the SHIFT routine with a DAD H instruction.

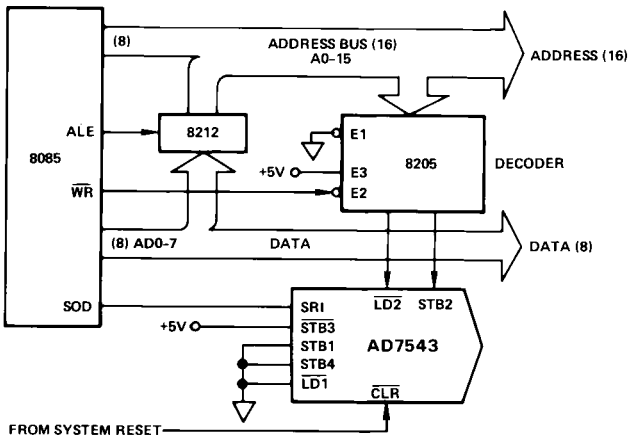
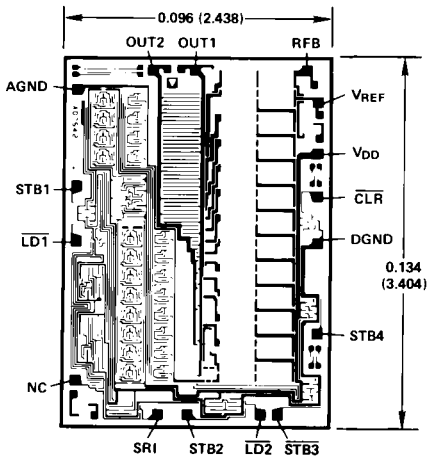


Figure 9. AD7543–8085 Interface

LABEL	MNEMONIC	OPERAND	COMMENT
	MVI	B, 05	Shift Data Up to
LOOP	CALL	SHIFT	Most Significant
	DCR	B	Segment of HL with
	JNZ	LOOP	MSB as Carry
	MVI	B, OC	
LUP	MVI	A, 80	SOD Enable in ACC
	RAR		Shift in MSB of H
	SIM		Set Interrupt Mask
	STA	8000	Strobe Data into AD7543
	CALL	SHIFT	Get Next Bit into Carry
	DCR	B	
	JNZ	LUP	Go Back if Not Finished
	STA	A000	Load DAC Register of AD7543
	RET		Return to Main Program
SHIFT	MOV	A, L	Shift H and L Left
	RAL		One Place and
	MOV	L, A	Leave Uppermost Bit
	MOV	A, H	of H in Carry
	RAL		
	MOV	H, A	
	RET		

Table VI. Sample Routine for AD7543–8085 Interface

BONDING DIAGRAM

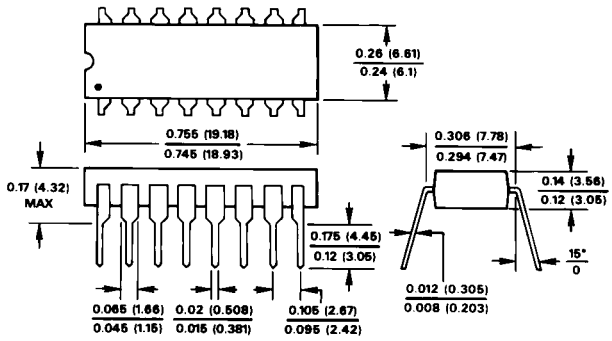


PADS ARE 0.004 × 0.004 INCHES (0.102 × 0.102mm) MIN.
TO MINIMIZE ESD HAZARD BOND DGND FIRST

OUTLINE DIMENSIONS

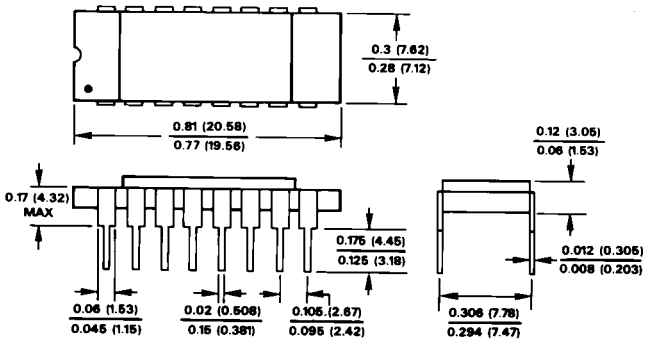
Dimensions shown in inches and (mm).

16-Pin Plastic DIP (N-16) Package



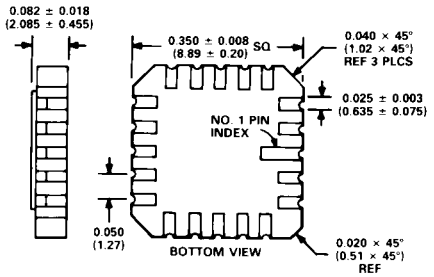
LEAD NO. 1 IDENTIFIED BY DOT OR NOTCH
LEADS ARE SOLDER OR TIN-PLATED KOVAR OR ALLOY 42

16-Pin Ceramic DIP (D-16) Package

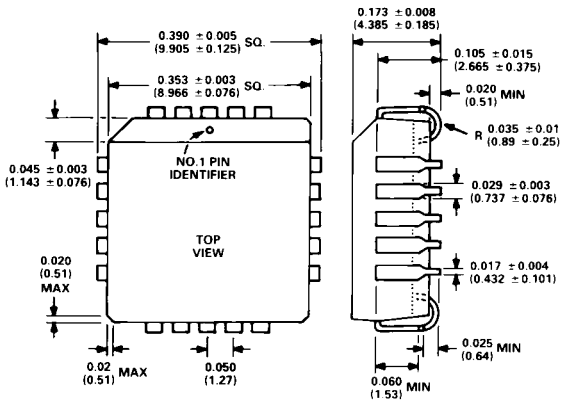


1. LEAD NO. 1 IDENTIFIED BY DOT OR NOTCH
2. LEADS WILL BE EITHER GOLD OR TIN PLATED IN ACCORDANCE WITH MIL-M-38510 REQUIREMENTS

20-Pin Leadless Ceramic Chip Carrier (E-20A) Package



20-Pin Plastic Leaded Chip Carrier (P-20A) Package



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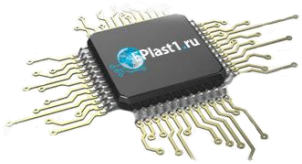
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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